

HM628128A Series

131,072-word × 8-bit High Speed CMOS Static RAM

The Hitachi HM628128A is a CMOS static RAM organized 128 kword × 8 bit. It realizes higher density, higher performance and low power consumption by employing 0.8 μm Hi-CMOS process technology.

It offers low power standby power dissipation; therefore, it is suitable for battery back-up systems.

The device, packaged in a 525-mil SOP (460-mil body SOP) or a 600-mil plastic DIP, or a 8 × 20 mm TSOP with thickness of 1.2 mm, is available for high density mounting. TSOP package is suitable for cards, and reverse type TSOP is also provided.

Features

- High speed
Fast access time: 55/70/85/100 ns (max)
- Low power
Active: 75 mW (typ)
Standby: 10 μW (typ) (L/L-L/L-SL version)
- Single 5 V supply
- Completely static memory
No clock or timing strobe required
- Equal access and cycle times
- Common data input and output
Three state output
- Directly TTL compatible
All inputs and outputs
- Capability of battery back up operation (L/L-L/L-SL version)
2 chip selection for battery back up

Ordering Information

Type No.	Access time	Package
HM628128ALP-5	55 ns	600-mil 32-pin plastic DIP (DP-32)
HM628128ALP-7	70 ns	
HM628128ALP-8	85 ns	
HM628128ALP-10	100 ns	
HM628128ALP-5L	55 ns	525-mil 32-pin plastic SOP (FP-32D)
HM628128ALP-7L	70 ns	
HM628128ALP-8L	85 ns	
HM628128ALP-10L	100 ns	

Type No.	Access time	Package
HM628128ALP-5SL	55 ns	600-mil 32-pin plastic DIP (DP-32)
HM628128ALP-7SL	70 ns	
HM628128ALP-8SL	85 ns	
HM628128ALP-10SL	100 ns	
HM628128ALFP-5	55 ns	525-mil 32-pin plastic SOP (FP-32D)
HM628128ALFP-7	70 ns	
HM628128ALFP-8	85 ns	
HM628128ALFP-10	100 ns	
HM628128ALFP-5L	55 ns	8 mm × 20 mm 32-pin TSOP (normal type) (TFP-32D)
HM628128ALFP-7L	70 ns	
HM628128ALFP-8L	85 ns	
HM628128ALFP-10L	100 ns	
HM628128ALFP-5SL	55 ns	8 mm × 20 mm 32-pin TSOP (reverse type) (TFP-32DR)
HM628128ALFP-7SL	70 ns	
HM628128ALFP-8SL	85 ns	
HM628128ALFP-10SL	100 ns	
HM628128ALT-5	55 ns	8 mm × 20 mm 32-pin TSOP (normal type) (TFP-32D)
HM628128ALT-7	70 ns	
HM628128ALT-8	85 ns	
HM628128ALT-10	100 ns	
HM628128ALT-5L	55 ns	8 mm × 20 mm 32-pin TSOP (reverse type) (TFP-32DR)
HM628128ALT-7L	70 ns	
HM628128ALT-8L	85 ns	
HM628128ALT-10L	100 ns	
HM628128ALR-5	55 ns	8 mm × 20 mm 32-pin TSOP (reverse type) (TFP-32DR)
HM628128ALR-7	70 ns	
HM628128ALR-8	85 ns	
HM628128ALR-10	100 ns	
HM628128ALR-5L	55 ns	8 mm × 20 mm 32-pin TSOP (reverse type) (TFP-32DR)
HM628128ALR-7L	70 ns	
HM628128ALR-8L	85 ns	
HM628128ALR-10L	100 ns	

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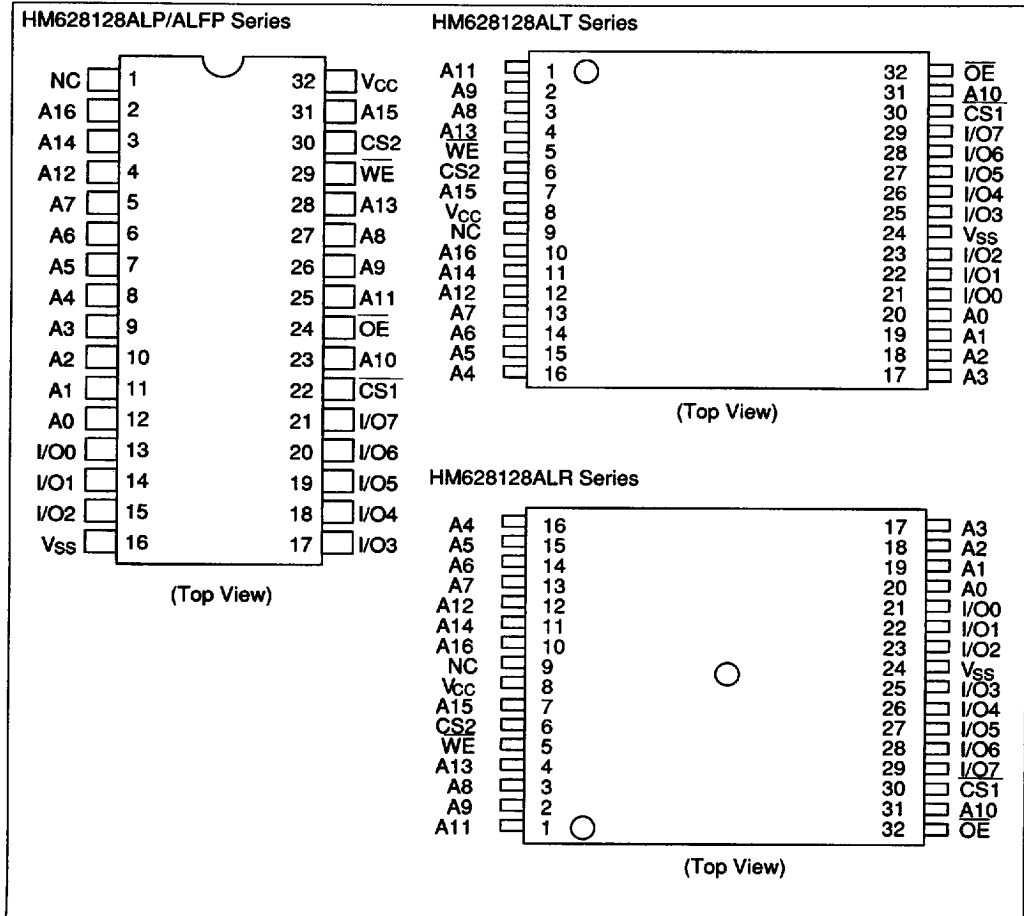
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Pin Arrangement



Pin Description

Pin name	Function
A0 – A16	Address
I/O0 – I/O7	Input/output
CS1	Chip select 1
CS2	Chip select 2
WE	Write enable

Pin name	Function
OE	Output enable
NC	No connection
Vcc	Power supply
Vss	Ground

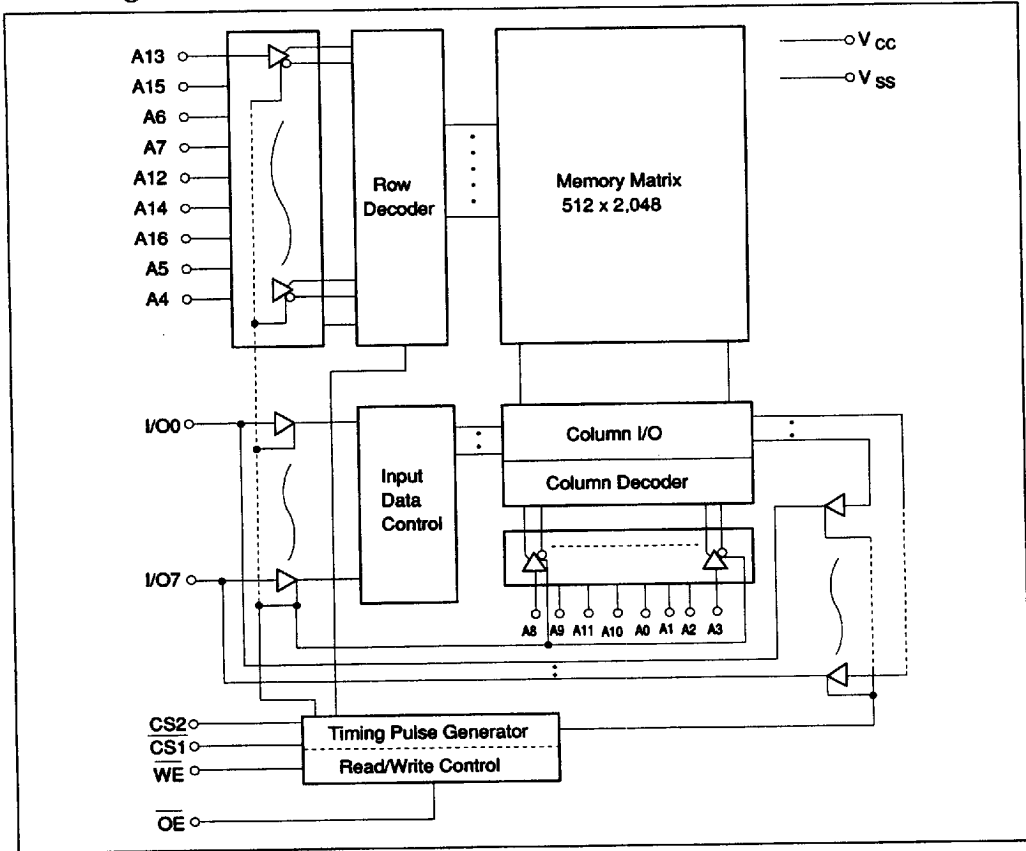
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Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply voltage relative to V _{SS}	V _{CC}	-0.5 to +7.0	V
Voltage on any pin relative to V _{SS}	V _T	-0.5 ¹ to V _{CC} + 0.3 ²	V
Power dissipation	P _T	1.0	W
Operating temperature	T _{opr}	0 to +70	°C
Storage temperature	T _{stg}	-55 to +125	°C
Storage temperature under bias	T _{bias}	-10 to +85	°C

Note: 1. -3.0 V for pulse half-width ≤ 30 ns
 2. Maximum voltage is 7.0V.

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Function Table

$\overline{CS1}$	$CS2$	\overline{OE}	\overline{WE}	Mode	V_{CC} current	I/O pin	Ref. cycle
H	X	X	X	Standby	I_{SB}, I_{SB1}	High-Z	—
X	L	X	X	Standby	I_{SB}, I_{SB1}	High-Z	—
L	H	H	H	Output disable	I_{CC}	High-Z	—
L	H	L	H	Read	I_{CC}	Dout	Read cycle
L	H	H	L	Write	I_{CC}	Din	Write cycle (1)
L	H	L	L	Write	I_{CC}	Din	Write cycle (2)

Note: 1. X: H or L

Recommended DC Operating Conditions ($T_a = 0$ to $+70^\circ\text{C}$)

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.5	5.0	5.5	V
	V_{SS}	0	0	0	V
Input voltage (HM628128A-7/8/10)	V_{IH}	2.2	—	$V_{CC} + 0.3$	V
	V_{IL}	-0.3^{*1}	—	0.8	V
Input voltage (HM628128A-5)	V_{IH}	2.4	—	$V_{CC} + 0.3$	V
	V_{IL}	-0.3^{*1}	—	0.8	V

Note: 1. -3.0 V for pulse half-width ≤ 30 ns

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DC Characteristics (Ta = 0 to +70°C, V_{CC} = 5 V ± 10%, V_{SS} = 0 V)

Parameter	Symbol	Min	Typ ^{*1}	Max	Unit	Test conditions	Notes
Input leakage current	I _{LI}	—	—	1.0	μA	V _{in} = V _{SS} to V _{CC}	
Output leakage current	I _{LO}	—	—	1.0	μA	CS1 = V _{IH} or CS2 = V _{IL} or OE = V _{IH} or WE = V _{IL} , V _{I/O} = V _{SS} to V _{CC}	
Operating power supply current: DC	I _{CC}	—	15	30	mA	CS1 = V _{IL} , CS2 = V _{IH} , Others = V _{IH} /V _{IL} I _{I/O} = 0 mA	
Operating power supply current	I _{CC1}	—	45	70	mA	Min cycle, duty = 100%, HM628128A CS1 = V _{IL} , CS2 = V _{IH} , -7/8/10 Others = V _{IH} /V _{IL}	HM628128A
		—	50	80	mA	I _{I/O} = 0 mA	-5
	I _{CC2}	—	15	25	mA	Cycle time = 1 μs, duty = 100%, I _{I/O} = 0 mA, CS1 ≤ 0.2 V, CS2 > V _{CC} - 0.2 V V _{IH} ≥ V _{CC} - 0.2 V, V _{IL} ≤ 0.2 V	
Standby power supply current: DC	I _{SB}	—	1	2	mA	CS1 = V _{IH} , CS2 = V _{IH} or CS2 = V _{IL}	
Standby power supply current (1): DC	I _{SB1}	—	0.02	2	mA	0 V ≤ V _{in} ≤ V _{CC} , CS1 ≥ V _{CC} - 0.2 V,	L-version
		—	2	100	μA	CS2 ≥ V _{CC} - 0.2 V or 0 V ≤ CS2 ≤ 0.2 V	
		—	2	50	μA		
Output voltage	V _{OL}	—	—	0.4	V	I _{OL} = 2.1 mA	
	V _{OH}	2.4	—	—	V	I _{OH} = -1.0 mA	

Note: 1. Typical values are at V_{CC} = 5.0 V, Ta = +25°C and specified loading.

Capacitance (Ta = 25°C, f = 1.0 MHz)*1

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Input capacitance	C _{in}	—	—	8	pF	V _{in} = 0 V
Input/output capacitance	C _{I/O}	—	—	10	pF	V _{I/O} = 0 V

Note: 1. This parameter is sampled and not 100% tested.

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AC Characteristics (Ta = 0 to +70°C, V_{CC} = 5 V ± 10%, unless otherwise noted.)

Test Conditions

- Input pulse levels: 0.8 V to 2.4 V (HM628128A-7/8/10)
0 V to 3 V (HM628128A-5)
- Input rise and fall times: 5 ns
- Input and output timing reference levels: 1.5 V
- Output load: 1 TTL Gate and CL (100 pF) (HM628128A-7/8/10)
1 TTL Gate and CL (30 pF) (HM628128A-5)
(Including scope & jig)

Read Cycle

		HM628128A									
		-5		-7		-8		-10			
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Notes
Read cycle time	t _{RC}	55	—	70	—	85	—	100	—	ns	
Address access time	t _{AA}	—	55	—	70	—	85	—	100	ns	
Chip selection to output valid	t _{CO1}	—	55	—	70	—	85	—	100	ns	
	t _{CO2}	—	55	—	70	—	85	—	100	ns	
Output enable to output valid	t _{OE}	—	30	—	35	—	45	—	50	ns	
Chip selection to output in low-Z	t _{LZ1}	5	—	10	—	10	—	10	—	ns	1, 2, 3
	t _{LZ2}	5	—	10	—	10	—	10	—	ns	1, 2, 3
Output enable to output in low-Z	t _{OLZ}	5	—	5	—	5	—	5	—	ns	1, 2, 3
Chip deselection to output in high-Z	t _{HZ1}	0	20	0	25	0	30	0	35	ns	1, 2, 3
	t _{HZ2}	0	20	0	25	0	30	0	35	ns	1, 2, 3
Output disable to output in high-Z	t _{OHZ}	0	20	0	25	0	30	0	35	ns	1, 2, 3
Output hold from address change	t _{OH}	5	—	10	—	10	—	10	—	ns	

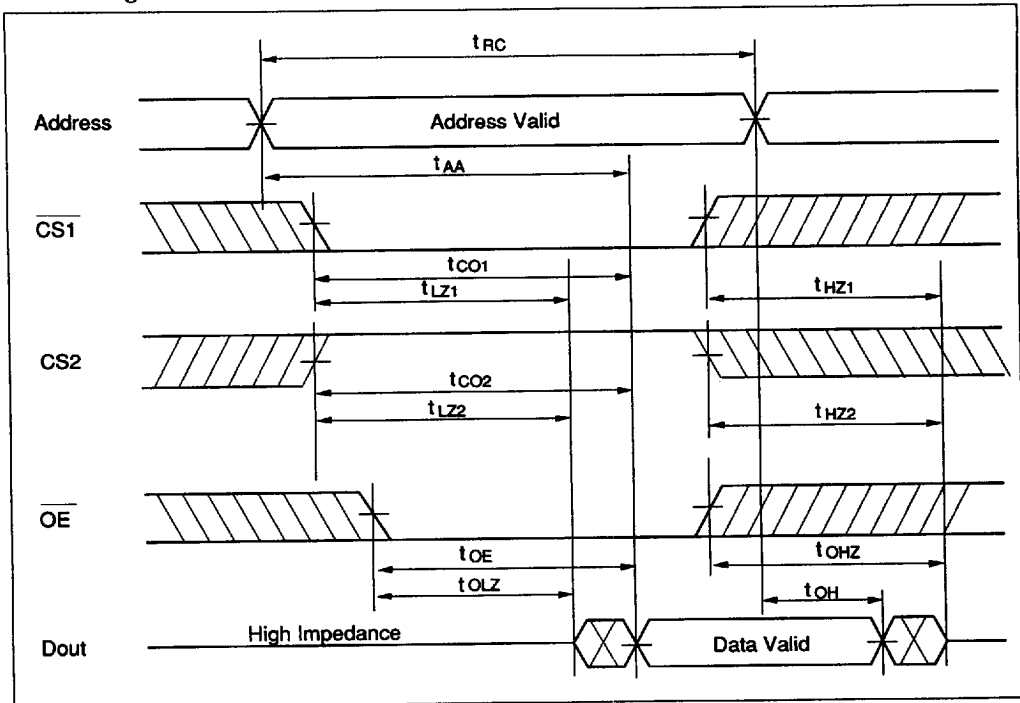
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Read Timing Waveform *4



- Notes:
1. t_{HZ} and t_{OHZ} are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
 2. At any given temperature and voltage condition, t_{HZ} max is less than t_{LZ} min both for a given device and from device to device.
 3. This parameter is sampled and not 100% tested.
 4. WE is high for read cycle.

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Write Cycle

Parameter	Symbol	HM628128A								Unit	Notes
		-5		-7		-8		-10			
		Min	Max	Min	Max	Min	Max	Min	Max		
Write cycle time	t_{WC}	55	—	70	—	85	—	100	—	ns	
Chip selection to end of write	t_{CW}	50	—	60	—	75	—	80	—	ns	
Address setup time	t_{AS}	0	—	0	—	0	—	0	—	ns	
Address valid to end of write	t_{AW}	50	—	60	—	75	—	80	—	ns	
Write pulse width	t_{WP}	40	—	50	—	55	—	60	—	ns	
Write recovery time	t_{WR}	0	—	0	—	0	—	0	—	ns	
		0	—	0	—	0	—	0	—	ns	11
Write to output in high-Z	t_{WHZ}	0	20	0	25	0	30	0	35	ns	10
Data to write time overlap	t_{DW}	25	—	30	—	35	—	40	—	ns	
Data hold from write time	t_{DH}	0	—	0	—	0	—	0	—	ns	
Output active from end of write	t_{OW}	5	—	5	—	5	—	5	—	ns	10

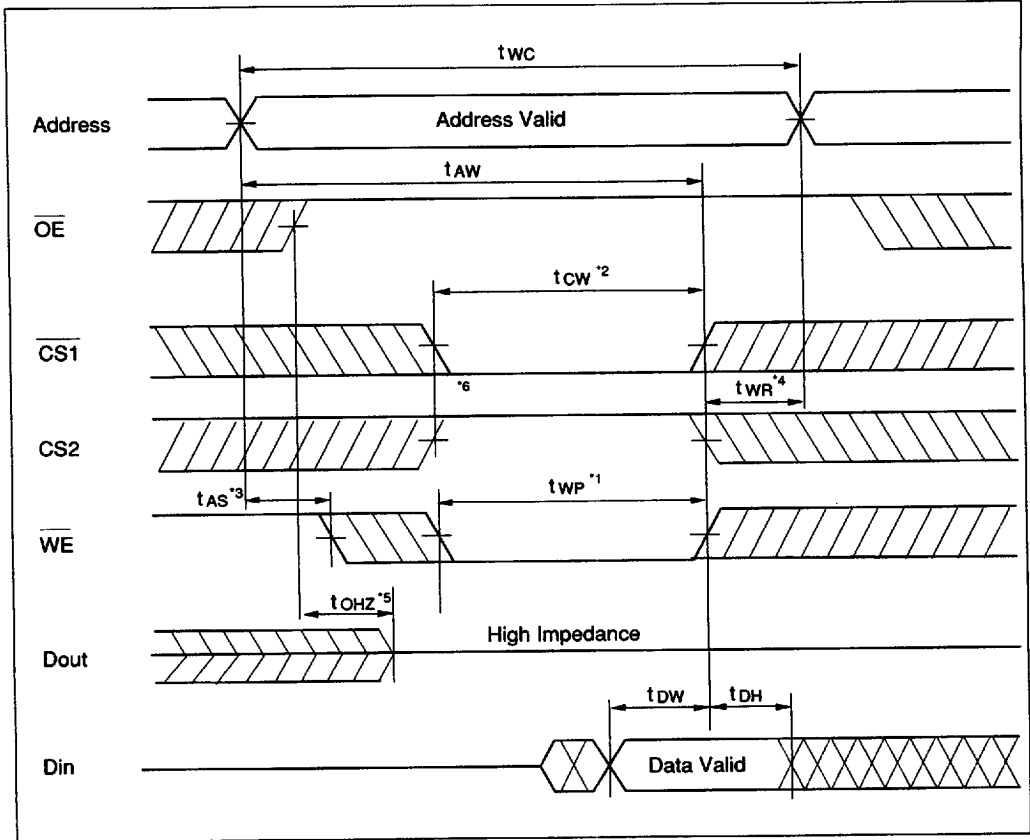
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Write Timing Waveform (1) (\overline{OE} Clock)



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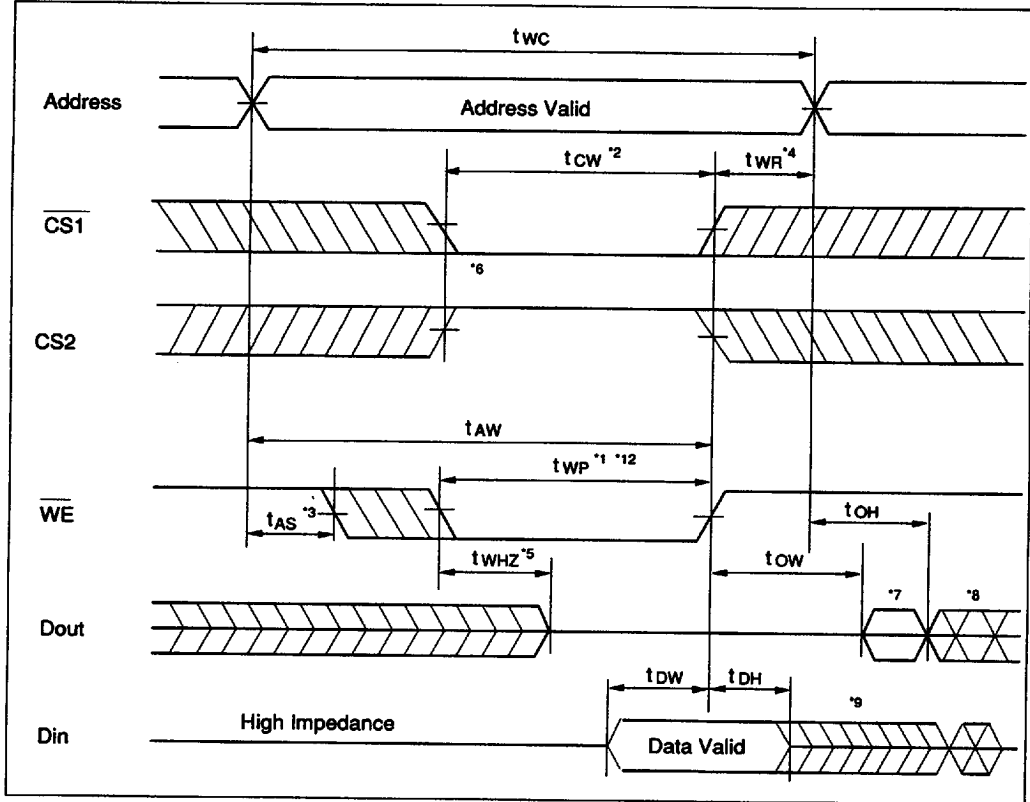
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Write Timing Waveform (2) (\overline{OE} low Fixed)



- Notes:
1. A write occurs during the overlap of a low $\overline{CS1}$, a high CS2, and a low WE. A write begins at the latest transition among $\overline{CS1}$ going low, CS2 going high, and WE going low. A write ends at the earliest transition among $\overline{CS1}$ going high, CS2 going low, and WE going high. t_{WP} is measured from the beginning of write to the end of write.
 2. t_{CW} is measured from the later of $\overline{CS1}$ going low or CS2 going high to the end of write.
 3. t_{AS} is measured from the address valid to the beginning of write.
 4. t_{WR} is measured from the earliest of $\overline{CS1}$ or WE going high or CS2 going low to the end of write cycle.
 5. During this period, I/O pins are in the output state; therefore, the input signals of the opposite phase to the outputs must not be applied.
 6. If the $\overline{CS1}$ goes low simultaneously with WE going low or after the WE going low, the outputs remain in a high impedance state.
 7. Dout is the same phase of the latest written data in this write cycle.
 8. Dout is the read data of next address.
 9. If $\overline{CS1}$ is low and CS2 high during this period, I/O pins are in the output state. Therefore, the input signals of opposite phase to the outputs must not be applied to them.
 10. This parameter is sampled and not 100% tested.
 11. This value is measured from CS2 going low to the end of write cycle.
 12. In the write cycle with \overline{OE} low fixed, t_{WP} must satisfy the following equation to avoid a problem of data bus contention.

$$t_{WP} \geq t_{DW} \text{ min} + t_{WHZ} \text{ max}$$

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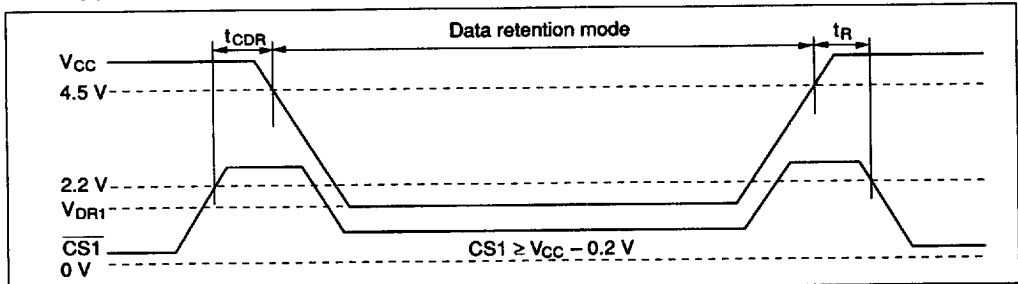
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Low V_{CC} Data Retention Characteristics (Ta = 0 to +70°C)

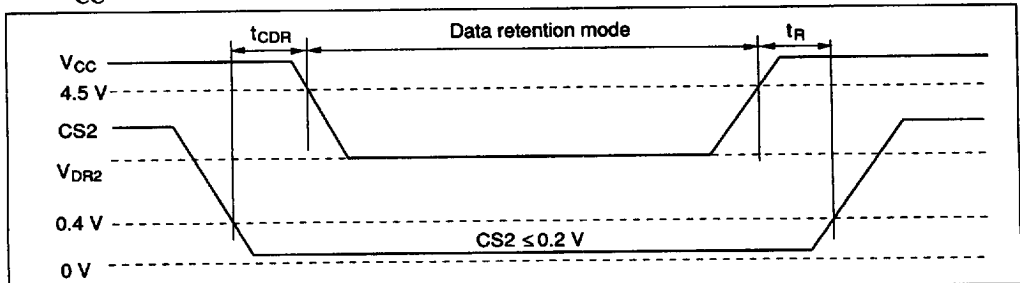
This characteristics is guaranteed only for L, L-L, and L-SL version.

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions	Notes
V _{CC} for data retention	V _{DR}	2.0	—	—	V	CS1 ≥ V _{CC} - 0.2 V, CS2 ≥ V _{CC} - 0.2 V or 0 V ≤ CS2 ≤ 0.2 V Vin ≥ 0 V	
Data retention current	I _{CCDR}	—	1	50 ¹	μA	V _{CC} = 3.0 V, Vin ≥ 0 V Lversion CS1 ≥ V _{CC} - 0.2 V	
		—	1	30 ²	μA	CS2 ≥ V _{CC} - 0.2 V or L-Lversion 0 V ≤ CS2 ≤ 0.2 V	
		—	1	15 ³	μA		L-Sversion
Chip deselect to data retention time	t _{CDR}	0	—	—	ns	See retention waveform	
Operation recovery time	t _R	5	—	—	ms		

Low V_{CC} Data Retention Timing Waveform (1) (CS1 Controlled)



Low V_{CC} Data Retention Timing Waveform (2) (CS2 Controlled)



- Notes:
- 20 μA max at Ta = 0 to 40°C (L version).
 - 6 μA max at Ta = 0 to 40°C (L-L version).
 - 3 μA max at Ta = 0 to 40°C (L-SL version).
 - CS2 controls address buffer, WE buffer, CS1 buffer, OE buffer, and Din buffer. If CS2 controls data retention mode, Vin levels (address, WE, OE, CS1, I/O) can be in the high impedance state. If CS1 controls data retention mode, CS2 must be CS2 ≥ V_{CC} - 0.2 V or 0 V ≤ CS2 ≤ 0.2 V. The other input levels (address, WE, OE, I/O) can be in the high impedance state.

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